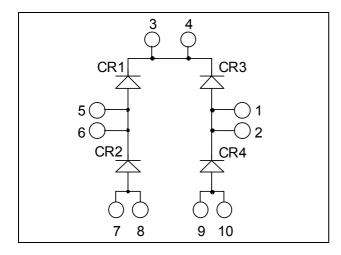
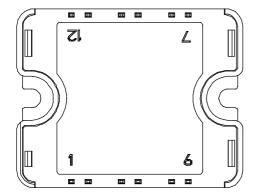


Fast Diode Full Bridge Power Module







All multiple inputs and outputs must be shorted together 3/4; 5/6; 7/8; 1/2; 9/10

Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit		
V_R	Maximum DC reverse Voltage			600	V		
V_{RRM}	Maximum Peak Repetitive Revers	e Voltage			000	V	
$I_{F(AV)}$	Maximum Average Forward	D. 4	500/	$T_C = 25^{\circ}C$	135 *		
	Current	Duty cycl	e = 50%	$T_C = 80$ °C	100 *	A	
I_{FSM}	Non-Repetitive Forward Surge Cu	irrent 8.3ms		$T_C = 45$ °C	500		

^{*} Specification of diode device but output current must be limited to 75A to not exceed a delta of temperature greater than 30°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

1 - 5



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{F}	Diode Forward Voltage	$I_F = 100A$			1.6	2.0	
		$I_F = 200A$			2.0		V
		$I_F = 100A$	$T_{j} = 125^{\circ}C$		1.3		
I_{RM}	Maximum Bayanga Laakaga Cumant	$T_{\rm j} = 25^{\circ}$	$T_j = 25^{\circ}C$			250	۸
	Maximum Reverse Leakage Current	$V_R = 600V$	$T_j = 125$ °C			500	μΑ
C_{T}	Junction Capacitance	$V_R = 200V$			190		pF

Dynamic Characteristics

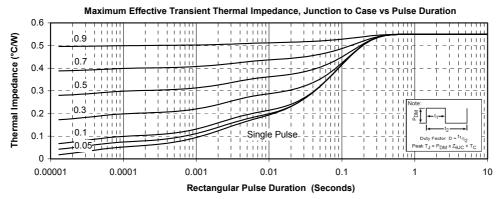
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit		
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		160		ns	
			$T_{j} = 125^{\circ}C$		220			
Q _{rr}	0	Reverse Recovery Charge	$I_F = 100A$ $V_R = 400V$	$T_j = 25^{\circ}C$		290		nC
	n Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 125^{\circ}C$		1530		110	
T	T	Reverse Recovery Current	•	$T_j = 25^{\circ}C$		5		A
1RKM	I _{RRM} Reverse Recovery Current		$T_j = 125$ °C		13		71	
t _{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 400V$ $di/dt = 1000A/\mu s$			100		ns	
Qrr	Reverse Recovery Charge		$T_j = 125$ °C		2890		nC	
I_{RRM}	Reverse Recovery Current				44		A	

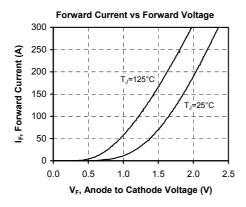
Thermal and package characteristics

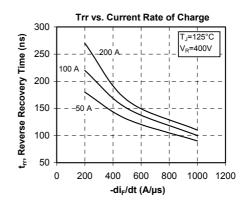
Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.55	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		175	°C
T_{STG}	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

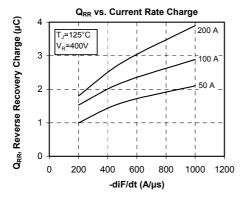


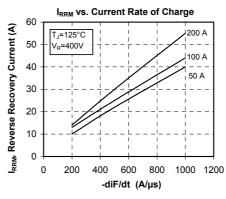
Typical Performance Curve

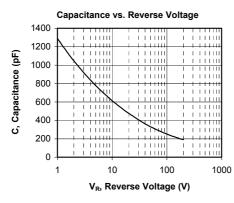


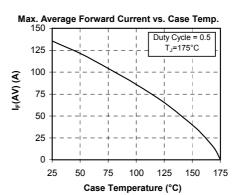






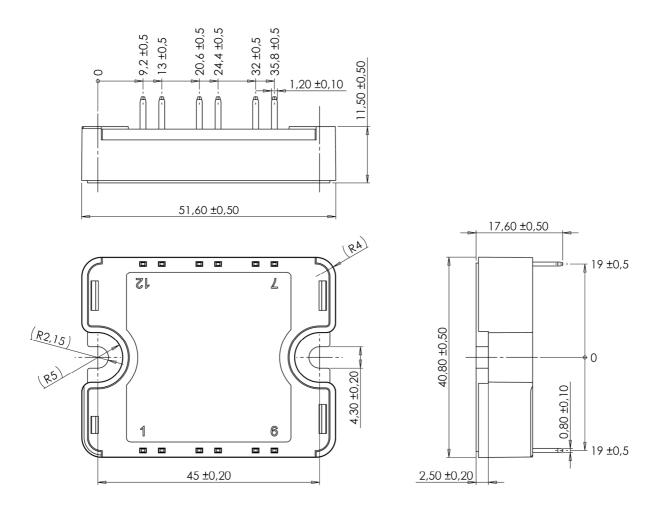








SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com



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